

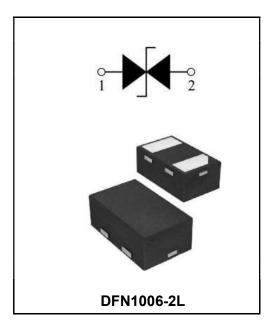
### **Bi-directional ESD Protection Diode**

#### **Features**

♦Capacitance: 15pF(typ.) ♦Reverse Working Voltage: 5V ♦IEC 61000-4-2 (ESD Air): ±25KV ♦IEC 61000-4-2 (ESD Contact): ±25KV ♦IEC 61000-4-5 (Lightning 8/20μs): 8.0A

## **Application**

- ♦Smart Phone and Tablet PC
- ♦TV and Set Top Box
- **♦**Wearable Devices
- **♦PDA**



Marking Code		
ESD1006B5V0C	PB	

## Limiting Values(TA = 25 °C, unless otherwise specified)

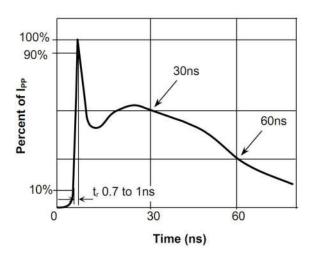
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>ESD</sub> Electrostatic Discharge Voltage	Floring the Dischause Valters	IEC 61000-4-2; Contact Discharge	-	±25	kV
	Electrostatic discharge voltage	IEC 61000-4-2; Air Discharge	-	±25	kV
P <sub>PP</sub>	Peak Pulse Power	tP = 8/20 μs		80	W
I <sub>PPM</sub>	Rated Peak Pulse Current	tP = 8/20 μs		8.0	Α
T <sub>A</sub>	Operating Temperature Range	-	<b>-</b> 55	125	$^{\circ}$
Tstg	Storage Temperature Range	-	-55	150	$^{\circ}$

## Electrical Characteristics(TA = 25 °C unless otherwise specified)

Symbol	Parameter	Conditions	Min	Тур.	Max	Unit
V <sub>RWM</sub>	Reverse Working Voltage	TA = 25 °C	-	-	5.0	٧
V <sub>BR</sub>	Breakdown Voltage	IR = 1mA; TA = 25 °C	5.6	6.5	8.4	V
I <sub>R</sub>	Reverse Leakage Current	VRWM = 5 V; TA = 25 °C	-	-	0.1	uA
V <sub>C</sub> Clamping Voltage	IPP=1 A, tP =8/20μs	-	-	6	V	
	Clamping voltage	IPP=8 A, tP =8/20μs	-	-	10	V
CJ	Junction Capacitance	VR = 0V, f = 1 MHz	-	15	18	pF



### **Typical Characteristics**



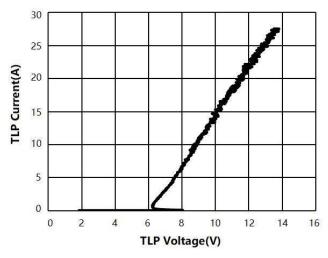
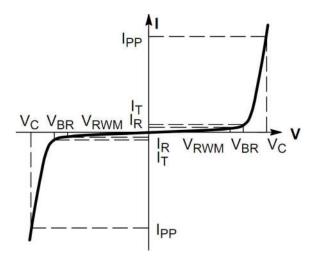


Fig.1 Pulse Waveform-ESD (IEC61000-4-2)

Fig.2 Transmission Line Pulse (TLP)



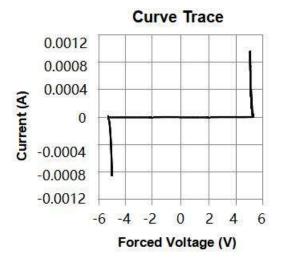
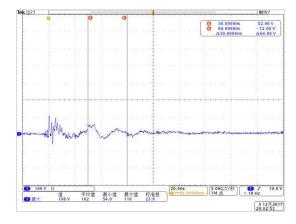


Fig.3 V-I Characteristics for Bidirectional Diode

Fig.4 IV Curve



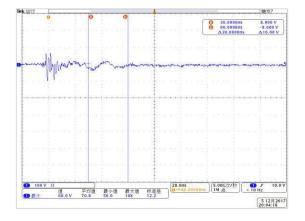
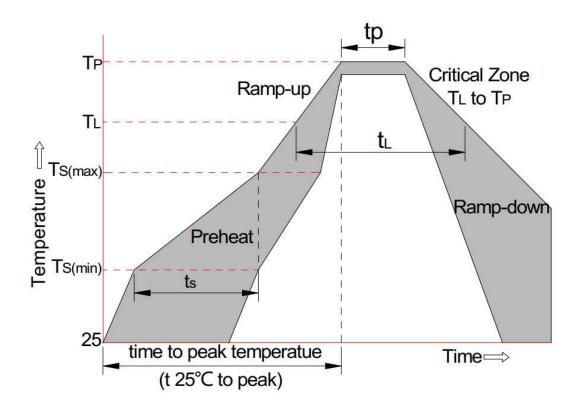


Fig.5 Clamping Voltage at IEC61000-4-2 +8kV Pulse Waveform

Fig.6 Clamping Voltage at IEC61000-4-2 -8kV Pulse Waveform



# **Soldering Parameters**



Reflow Condition		Pb-Free Assembly	
	-Temperature Min (Ts(min))	+150°C	
Pre-heat	-Temperature Max(Ts(max))	+200°C	
	-Time (Min to Max) (ts)	60-180 secs.	
Average ramp up rate (Liquid us Temp (TL) to peak)		3°C/sec. Max	
Ts(max) to TL - Ramp-up Rate		3°C/sec. Max	
Doffour	-Temperature(TL)(Liquid us)	+217°C	
Reflow	-Temperature(tL)	60-150 secs.	
Peak Temp (Tp)		+260(+0/-5)°C	
Time within 5°C of actual Peak Temp (tp)		30 secs. Max	
Ramp-down Rate		6°C/sec. Max	
xTime 25°C to Peak Temp (TP)		8 min. Max	
Do not exceed		+260°C	

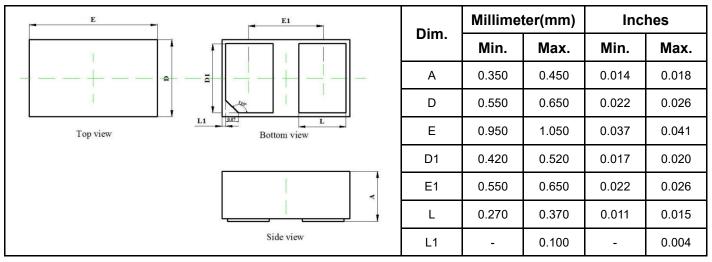


## **Ordering information**

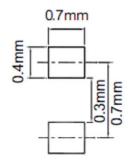
Package	Packing Description	Packing Quantity
DFN1006-2L	Tape/Reel,7"reel	10000PCS/Reel 400000PCS/Carton

## **Package Dimensions**

## **DFN1006-2L**



## The recommended mounting pad size





# **Disclaimer**

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